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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RENESAS

MOS FIELD EFFECT TRANSISTOR NP82N06PDG

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP82N06PDG is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP82N06PDG-E1-AY Note	Pure Sn (Tin)	Tape	TO-263 (MP-25ZP)
NP82N06PDG-E2-AY Note		800 p/reel	typ. 1.5 g

Note See "TAPE INFORMATION"

FEATURES

• Super low on-state resistance $R_{DS(on)1} = 6.7 \text{ m}\Omega \text{ MAX.}$ (VGs = 10 V, ID = 41 A) $R_{DS(on)2} = 8.5 \text{ m}\Omega \text{ MAX.}$ (VGs = 5 V, ID = 41 A) • Low Ciss

Ciss = 5700 pF TYP.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	60	V		
Gate to Source Voltage (VDs = 0 V)	Vgss	±20	V		
Drain Current (DC) (Tc = 25° C)	ID(DC)	±82	А		
Drain Current (pulse) Note1	D(pulse)	±270	А		
Total Power Dissipation (Tc = 25° C)	PT1	143	W		
Total Power Dissipation (T _A = 25° C)	P T2	1.8	W		
Channel Temperature	Tch	175	°C		
Storage Temperature	Tstg	–55 to +175	°C		
Repetitive Avalanche Current Note2	IAR	37	А		
Repetitive Avalanche Energy Note2	Ear	137	mJ		
Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%					
2. T _{ch} \leq 150°C, V _{DD} = 30 V, R _G = 25 Ω , V _{GS} = 20 \rightarrow 0 V					

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	1.05	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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(TO-263)



Document No. D18227EJ1V0DS00 (1st edition) Date Published June 2006 NS CP(K) Printed in Japan

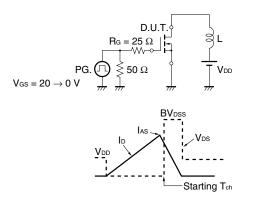
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	Vds = 60 V, Vgs = 0 V			1	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±100	nA
Gate to Source Threshold Voltage Note	VGS(th)	$V_{DS} = V_{GS}$, $I_D = 250 \mu$ A	1.5	2.0	2.5	V
Forward Transfer Admittance Note	y _{fs}	Vds = 10 V, Id = 41 A	19	45		S
Drain to Source On-state Resistance Note	RDS(on)1	Vgs = 10 V, Id = 41 A		5.1	6.7	mΩ
	RDS(on)2	Vgs = 5 V, Id = 41 A		6.0	8.5	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V		5700		pF
Output Capacitance	Coss	Vgs = 0 V		420		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		275		pF
Turn-on Delay Time	td(on)	Vdd = 30 V		28		ns
Rise Time	tr	I _D = 41 A		22		ns
Turn-off Delay Time	td(off)	Vgs = 10 V		79		ns
Fall Time	tr	Rg = 0 Ω		9		ns
Total Gate Charge	QG	Vdd = 48 V		106		nC
Gate to Source Charge	Q _{GS}	Vgs = 10 V		29		nC
Gate to Drain Charge	Qgd	ID = 82 A		35		nC
Body Diode Forward Voltage	VF(S-D)	IF = 82 A, VGS = 0 V		0.9	1.5	V
Reverse Recovery Time	trr	IF = 82 A, VGS = 0 V		43		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		65		nC

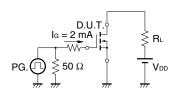
Note Pulsed

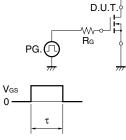
TEST CIRCUIT 1 AVALANCHE CAPABILITY

TEST CIRCUIT 2 SWITCHING TIME

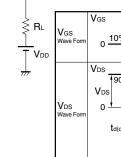


TEST CIRCUIT 3 GATE CHARGE



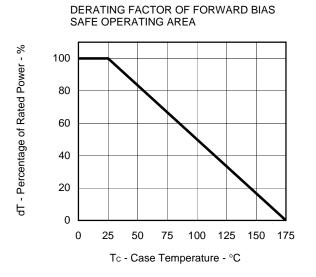


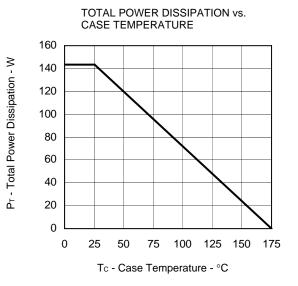
 $\tau = 1 \,\mu s$ Duty Cycle $\leq 1\%$



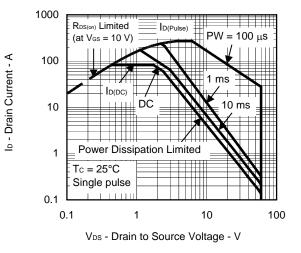
VGS Wave Form	$V_{GS} = \frac{10\%}{V_{GS}} + \frac{V_{GS}}{V_{GS}} + \frac{90\%}{V_{GS}}$
VDS Wave Form	$V_{DS} \underbrace{\begin{array}{c c} & & & \\ V_{DS} \\ 0 \\ t_{d(on)} \\ t_{d(on)} \\ t_{d(on)} \\ t_{on} \\ $

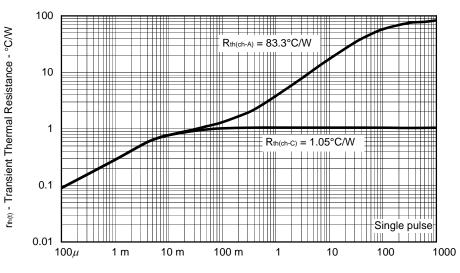
TYPICAL CHARACTERISTICS (TA = 25°C)





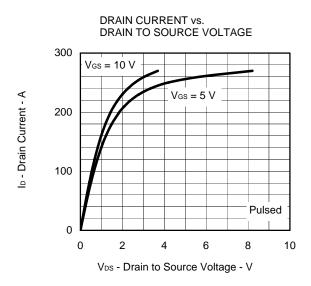
FORWARD BIAS SAFE OPERATING AREA



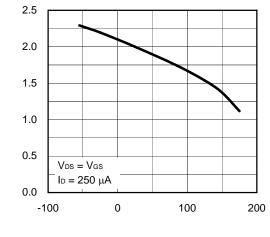


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

PW - Pulse Width - s

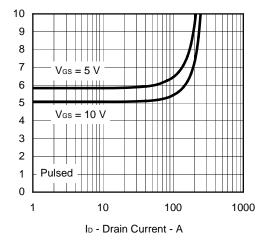


GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

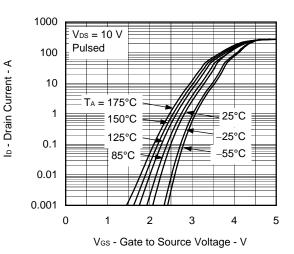


Tch - Channel Temperature - °C

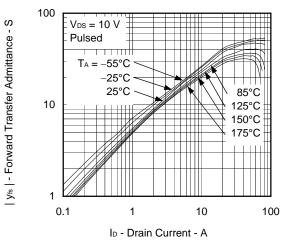
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



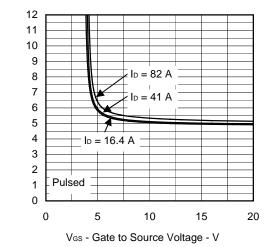
FORWARD TRANSFER CHARACTERISTICS



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



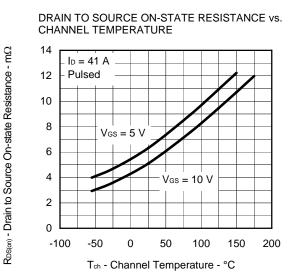
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



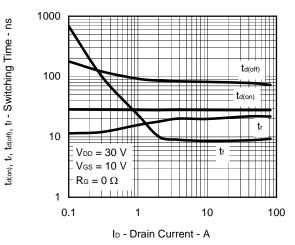
V_{GS(th)} - Gate to Source Threshold Voltage - V

 $R_{DS(cn)}$ - Drain to Source On-state Resistance - $m\Omega$

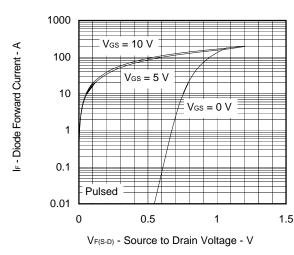
S



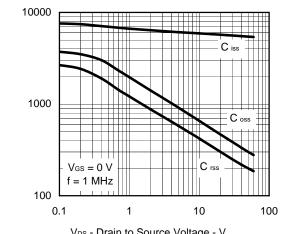




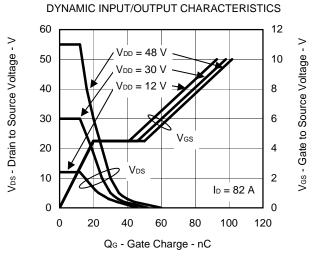
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



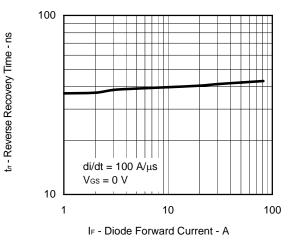
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



Ciss, Coss, Crss - Capacitance - pF



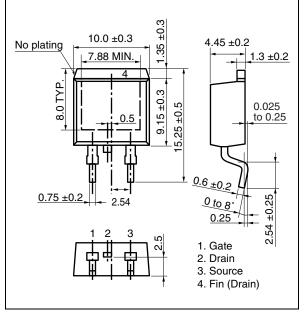
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



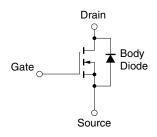
VDS - Drain to Source Voltage - V

PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZP)



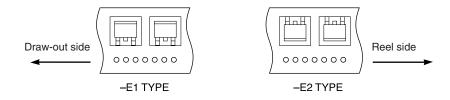
EQUIVALENT CIRCUIT



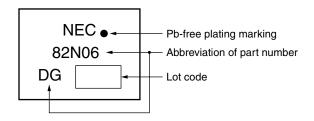
Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

TAPE INFORMATION

There are two types (-E1, -E2) of taping depending on the direction of the device.



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

The NP82N06PDG should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (http://www.necel.com/pkg/en/mount/index.html)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Maximum temperature (Package's surface temperature): 260°C or below	IR60-00-3
	Time at maximum temperature: 10 seconds or less	
	Time of temperature higher than 220°C: 60 seconds or less	
	Preheating time at 160 to 180°C: 60 to 120 seconds	
	Maximum number of reflow processes: 3 times	
	Maximum chlorine content of rosin flux (percentage mass): 0.2% or less	
Partial heating	Maximum temperature (Pin temperature): 350°C or below	P350
	Time (per side of the device): 3 seconds or less	
	Maximum chlorine content of rosin flux: 0.2% (wt.) or less	

Caution Do not use different soldering methods together (except for partial heating).

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